

Parameter	Tr1 and Tr2
V_{CEO}	-20V
I_C	-200mA

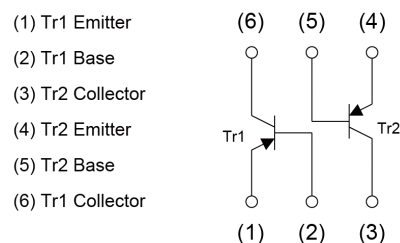
●Outline

VMT6  VT6T1	EMT6  EMT51 (SC-107C)
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●Features

- 1) General Purpose.
- 2) Two 2SAR522 chips in one package.
- 3) Transistor elements are independent, eliminating interface.
- 4) Mounting cost and area can be cut in half.
- 5) Lead Free/RoHS Compliant.

●Inner circuit



●Application

Switching, LED driver

●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
VT6T1	VMT6	1212	T2R	180	8	8000	T1
EMT51	EMT6	1616	T2R	180	8	8000	T51

● **Absolute maximum ratings** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	-20	V
Collector-emitter voltage		V_{CEO}	-20	V
Emitter-base voltage		V_{EBO}	-5	V
Collector current		I_C	-200	mA
		I_{CP}^{*1}	-400	mA
Power dissipation	VT6T1	P_D^{*2*3}	150	mW
	EMT51		150	
Junction temperature		T_j	150	$^\circ\text{C}$
Range of storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

● **Electrical characteristics** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV_{CBO}	$I_C = -50\mu\text{A}$	-20	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = -1\text{mA}$	-20	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_E = -50\mu\text{A}$	-5	-	-	V
Collector cut-off current	I_{CBO}	$V_{CB} = -20\text{V}$	-	-	-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{V}$	-	-	-0.1	μA
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100\text{mA}$, $I_B = -10\text{mA}$	-	-0.12	-0.30	V
DC current gain	h_{FE}	$V_{CE} = -6\text{V}$, $I_C = -1\text{mA}$	120	-	560	-
Transition frequency	f_T	$V_{CE} = -10\text{V}$, $I_E = 10\text{mA}$, $f = 100\text{MHz}$	-	350	-	MHz
Output capacitance	C_{ob}	$V_{CB} = 10\text{V}$, $I_E = 0\text{A}$, $f = 1\text{MHz}$	-	1.6	-	pF

*1 $P_w=1\text{ms}$ Single Pulse

*2 Each terminal mounted on a reference footprint

*3 120mW per element must not be exceeded.

●Electrical characteristic curves(Ta=25°C)

<For Tr1 and Tr2 in common>

Fig.1 Grounded Emitter Propagation Characteristics

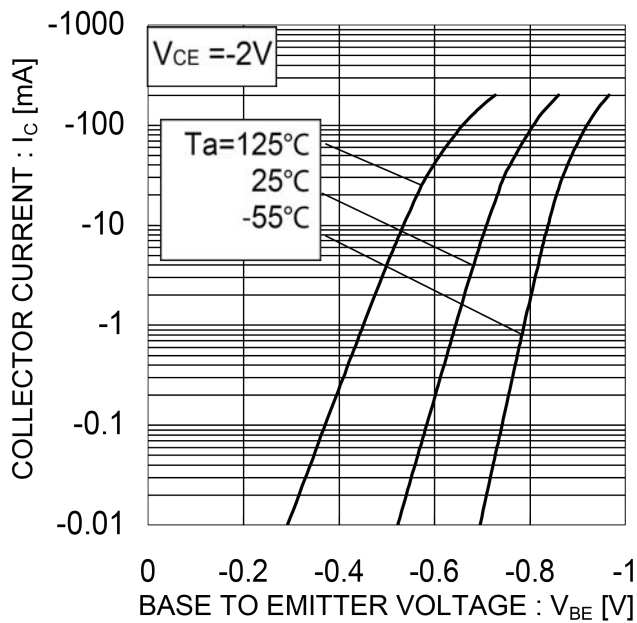


Fig.2 Typical Output Characteristics

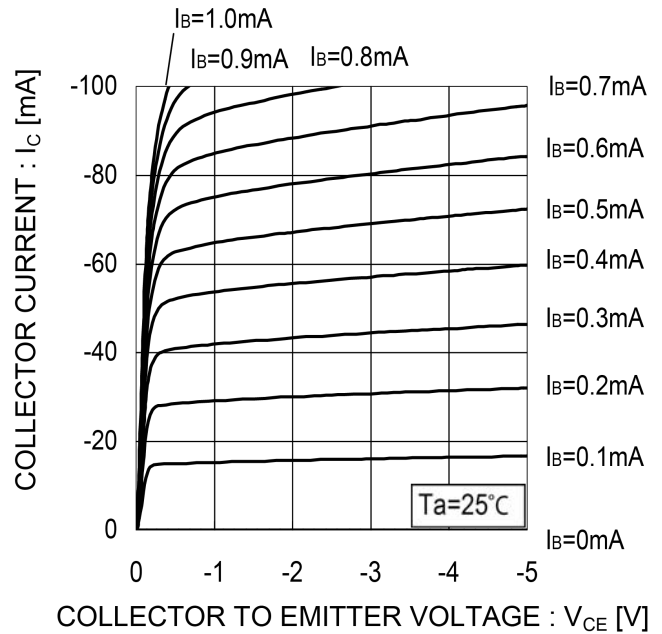


Fig.3 DC Current Gain vs. Collector Current(I)

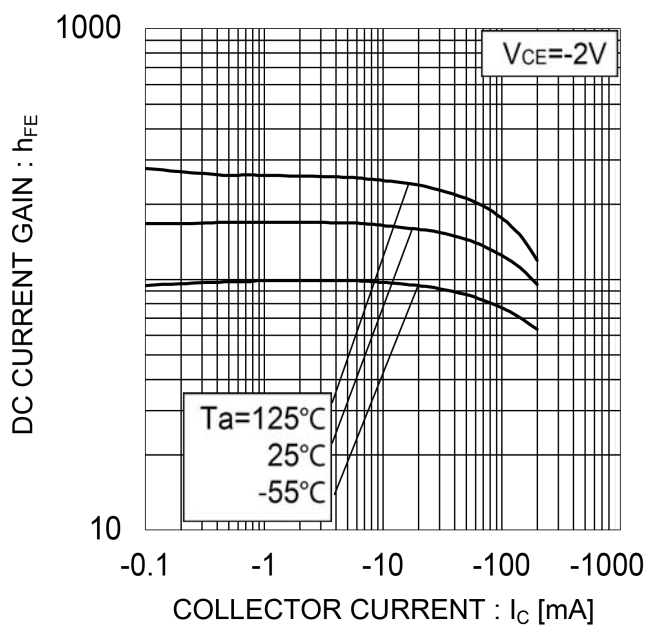
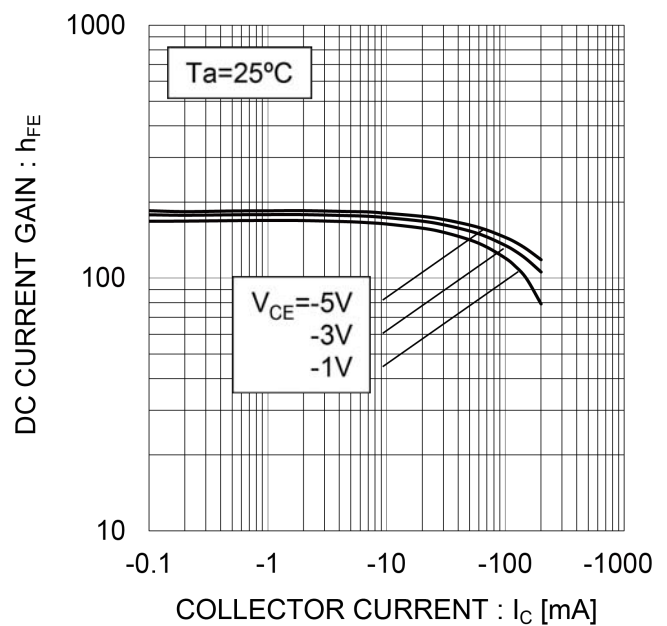


Fig.4 DC Current Gain vs. Collector Current(II)



● **Electrical characteristic curves** ($T_a=25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

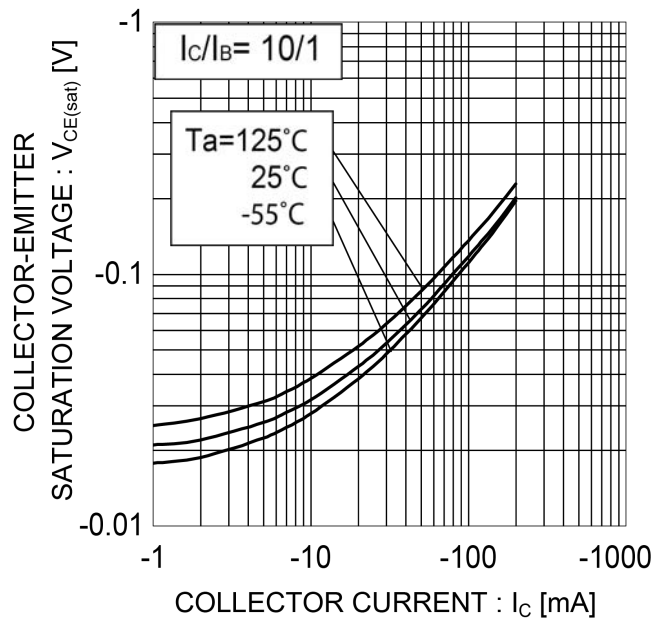


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

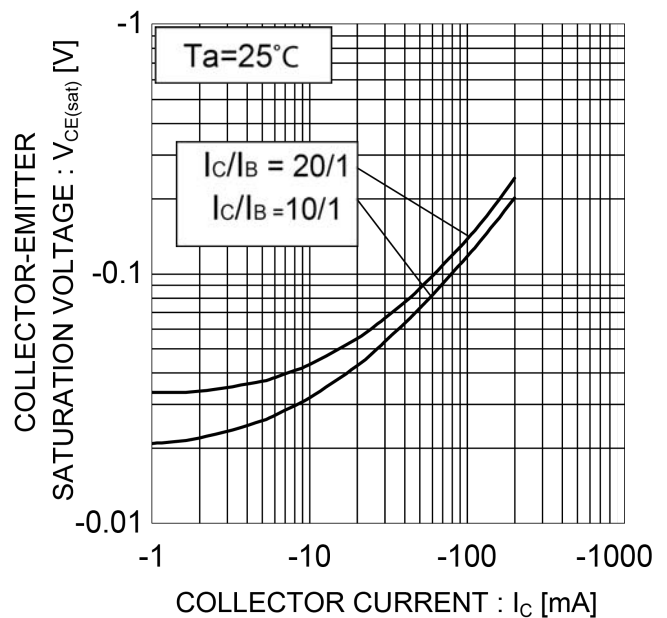


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

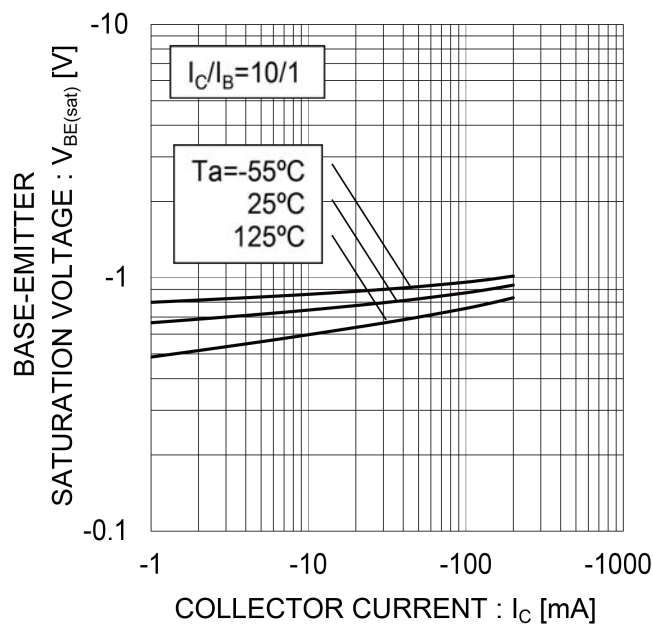
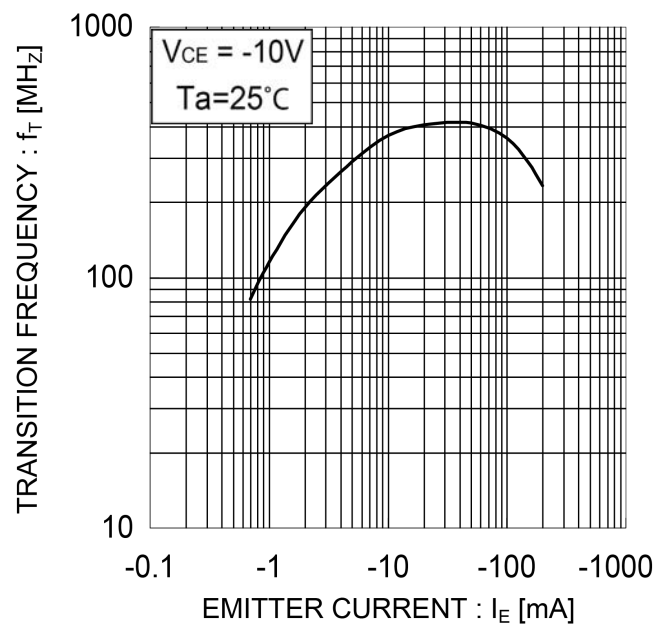


Fig.8 Gain Bandwidth Product vs. Emitter Current



● **Electrical characteristic curves** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Fig.9 Emitter input capacitance Collector output capacitance

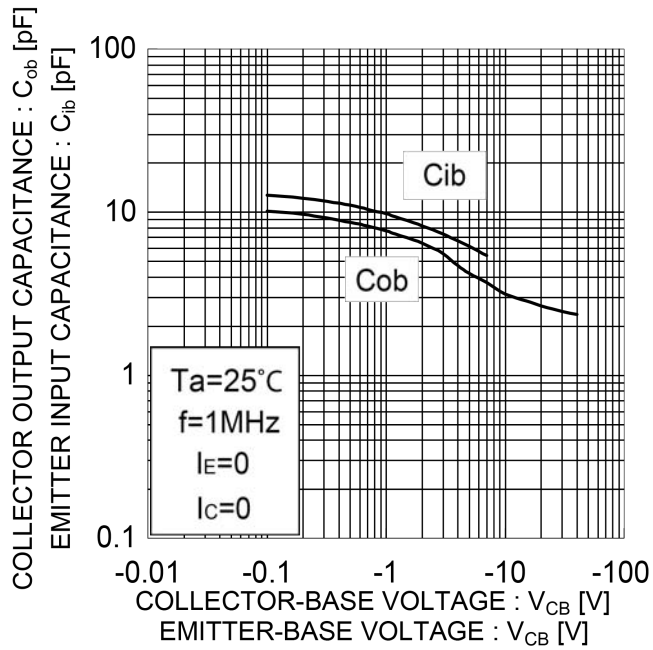
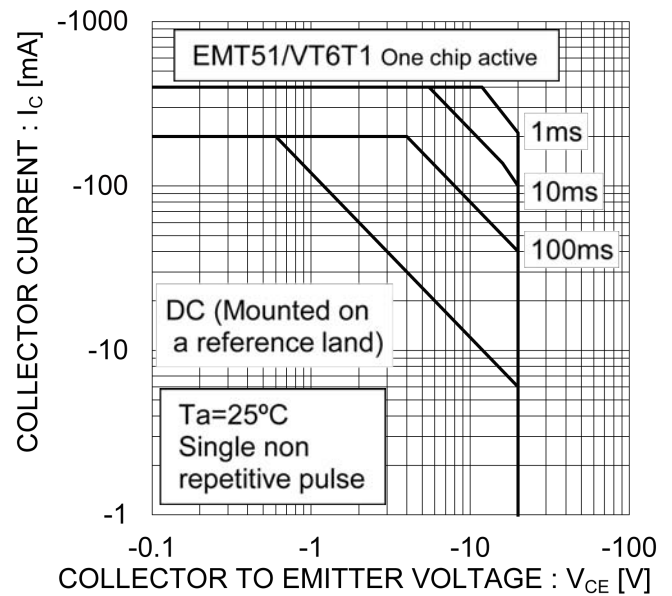
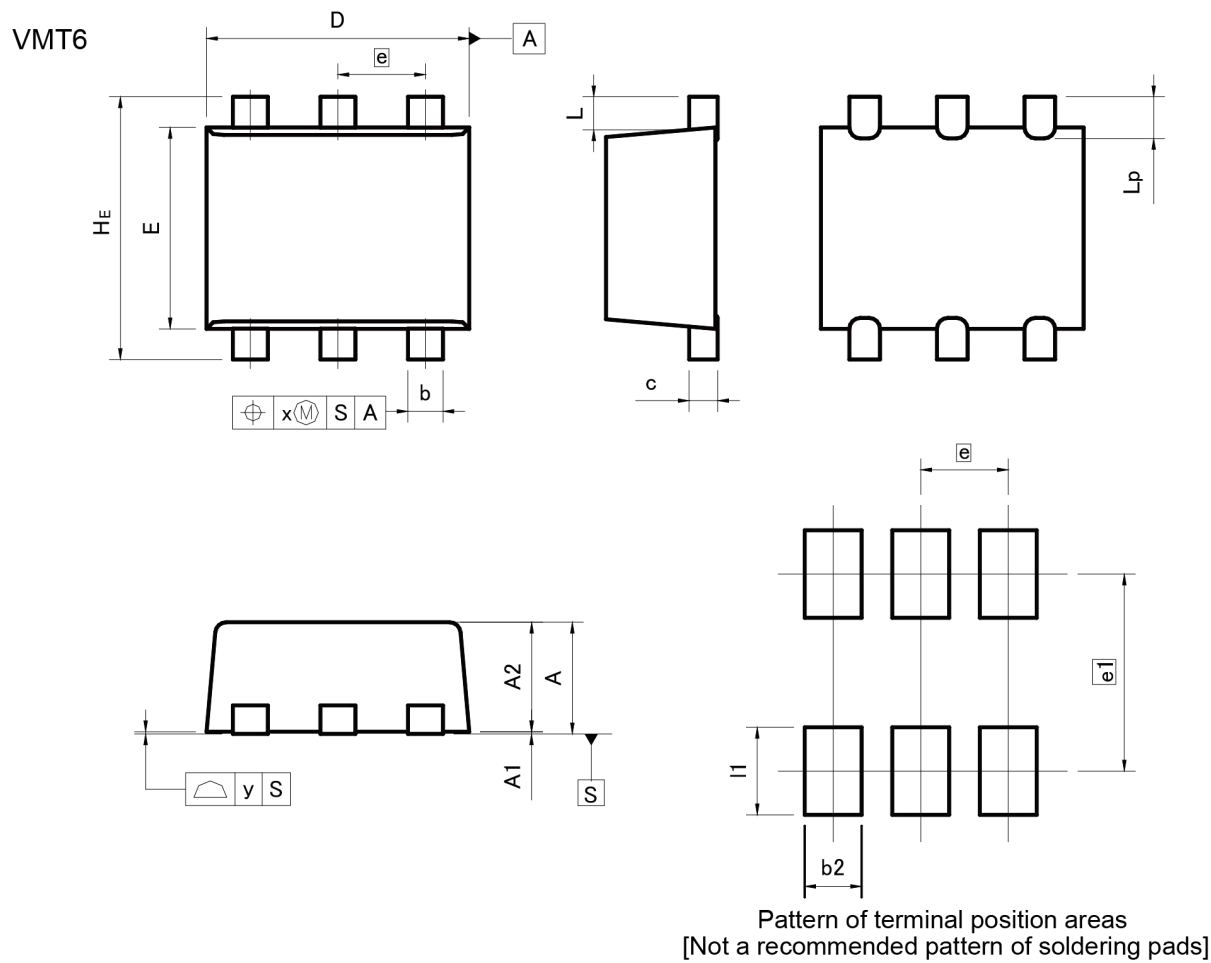


Fig.10 Safe Operating Area



●Dimensions

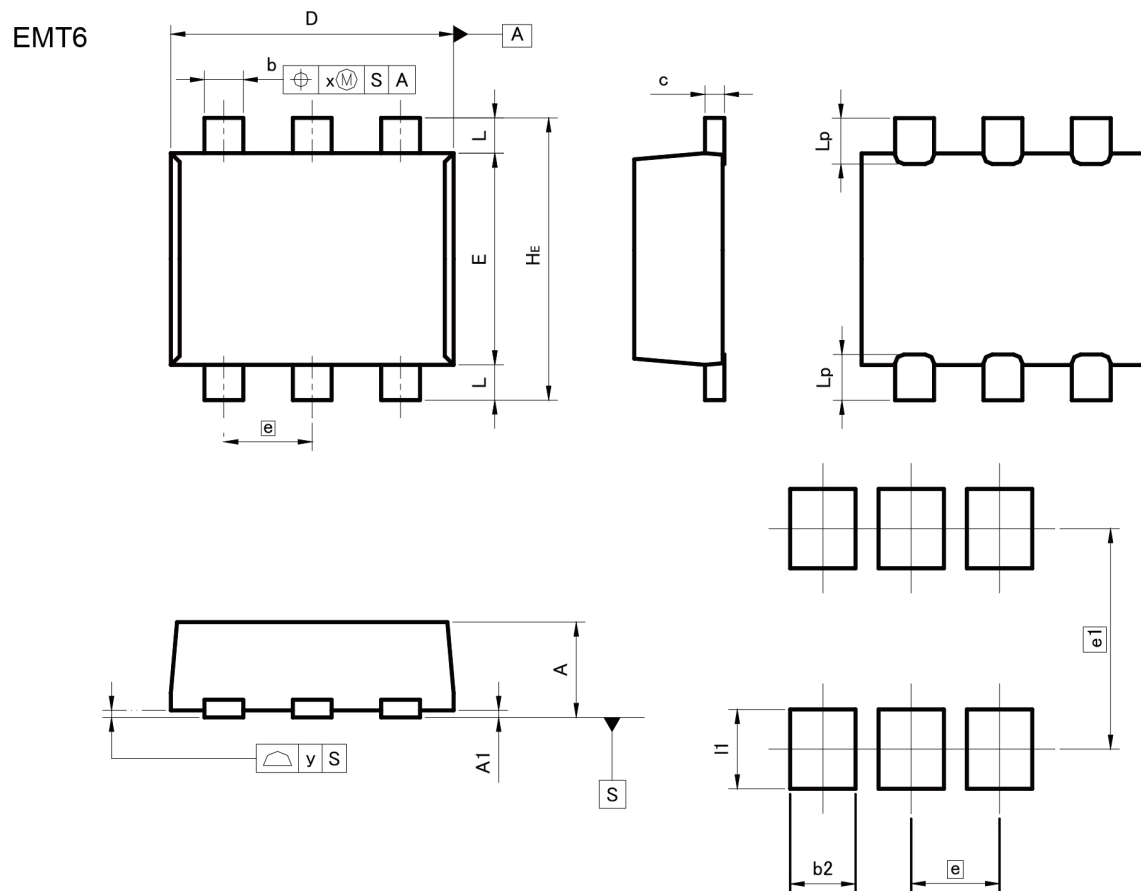


DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.42	0.62	0.017	0.024
A1	0.00	0.05	0.000	0.002
A2	0.40	0.60	0.016	0.024
b	0.11	0.21	0.004	0.008
c	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.82	1.02	0.032	0.04
e	0.40		0.016	
HE	1.10	1.30	0.043	0.051
L	0.14		0.006	
Lp	0.10	0.30	0.004	0.012
x	—	0.05	—	0.002
y	—	0.10	—	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	—	0.26	—	0.010
e1	0.90		0.035	
l1	—	0.40	—	0.016

Dimension in mm/inches

●Dimensions



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
e	0.50		0.020	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	–	0.35	–	0.014
x	–	0.10	–	0.004
y	–	0.10	–	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	–	0.37	–	0.015
e1	1.25		0.049	
I1	–	0.45	–	0.018

Dimension in mm/inches

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